

# PT85QWx45

# **Pulse Power Thyristor Switch**

Replaces DS5334-2 DS5334-3 March 2023 (LN42490)

#### **FEATURES**

- Double Side Cooling
- Fast Turn-on
- Low Turn-on Losses

#### **APPLICATIONS**

- Pulse Power
- Crowbars
- Ignitron Replacement

#### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages VDRM and VRRM (V)	Conditions
PT85QWx45	4500/16	$T_{Vj} = 0$ °C to 125°C, IDRM = IRRM = 250mA, $VDRM$ , $VRRM$ $t_P = 10ms$

Lower voltage grades available.

#### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

### PT85QWx45

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

See "additional ordering information" on page 5 regarding lead length (x).

#### **KEY PARAMETERS**

VDRM 4500V Iτ(AV) 1670A Iτsм 37000A dI/dt 22000A/μs

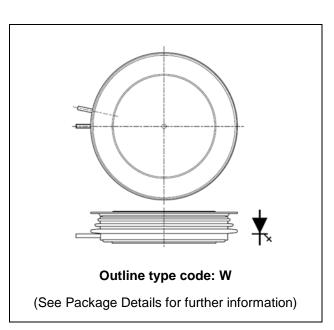


Fig. 1 Package outline

www.dynexsemi.com 1/7

## **CURRENT RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
IT(AV)	Mean on-state current	Half wave resistive load, Tcase = 80°C	1670	Α
IT(RMS)	RMS value	-	2622	Α

# **SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
Ітѕм	Surge (non-repetitive) on-state current	10ms half sine, Tcase = 125°C	29.6	kA
l²t	I <sup>2</sup> t for fusing	Vr = 50% Vrrm	4.38	MA <sup>2</sup> s
Ітѕм	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 125°C	37.0	kA
l²t	I2t for fusing	V <sub>R</sub> = 0	6.85	MA <sup>2</sup> s

## THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
Rth(j-c)	Thermal resistance - junction to case	Double side cooled	DC	-	10.0	°C/kW
Rth(c-h)	Thermal resistance - case to heatsink	Clamping force 36kN	Double side	-	1.0	°C/kW
-	Violentia di controlo di contr	Blocking VDRM / VRRM		-	125	°C
Tvj Virtual junction temperature		On-state (conducting)		-	135	°C
Tstg	tg Storage temperature range		-55	125	°C	
Fm	Clamping force			36	44	kN

www.dynexsemi.com 2/7

# **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditions		Min.	Max.	Units
IRRM/IDRM	Peak reverse and off-state current	At VRRM/VDRM, Tcase = 125°C		-	250	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% Vdrm, Tj = 125°C, Rgk $\leq$ 1.5 $\Omega$		-	200	V/µs
dl/dt	Rate of rise of on-state current	From 67% VDRM to 20kA Gate source 30A tr < 1.5µs, Tj = 125°C	Non-repetitive	-	22	kA/μs
<b>V</b> т(то)	Threshold voltage	Tvj = 125°C		-	1.45	V
ľτ	On-state slope resistance - low level	Tcase = 125°C		-	0.3	mΩ

## **GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter	Test Conditions	Min.	Max.	Units
<b>V</b> GT	Gate trigger voltage	VD = 24V, IT = 100A, Tvj = 25°C	-	1.5	V
Іст	Gate trigger current	VD = 24V, II = 100A, IVJ = 25 C	1.0	4.0	А

www.dynexsemi.com 3/7

# **CURVES**

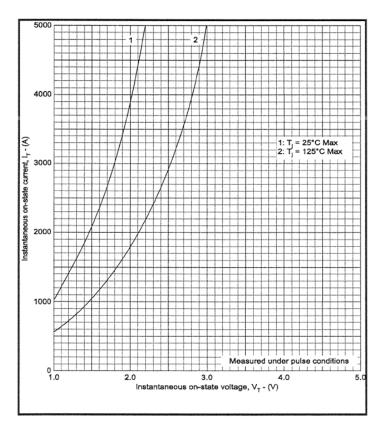


Fig. 2 Maximum (limit) on-state characteristics

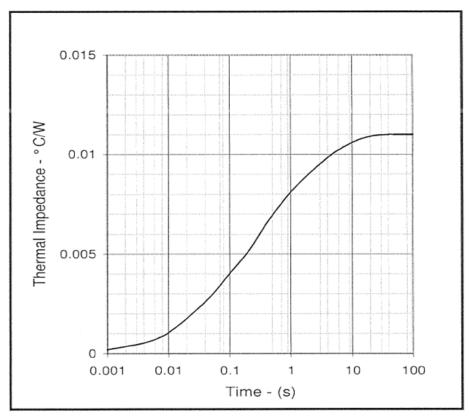


Fig.3 Maximum (limit) transient thermal impedance - double side cooled

www.dynexsemi.com 4/7

## **ADDITIONAL ORDERING INFORMATION**

PT Pulse Power Thyristor

85Q Device type

W Package outline type codex Lead length (see table, right)

45 Voltage x100

Lead length (x)				
О	No lead			
С	8"	200mm		
D	10"	250mm		
E	12"	300mm		
F	16"	400mm		
G	18"	450mm		
Н	20"	500mm		
J	24"	600mm		
K	30"	750mm		
L	40"	1000mm		

www.dynexsemi.com 5/7

### **PACKAGE DETAILS**

For further package information, please contact Customer services.

All dimensions in mm, unless stated otherwise.

DO NOT SCALE

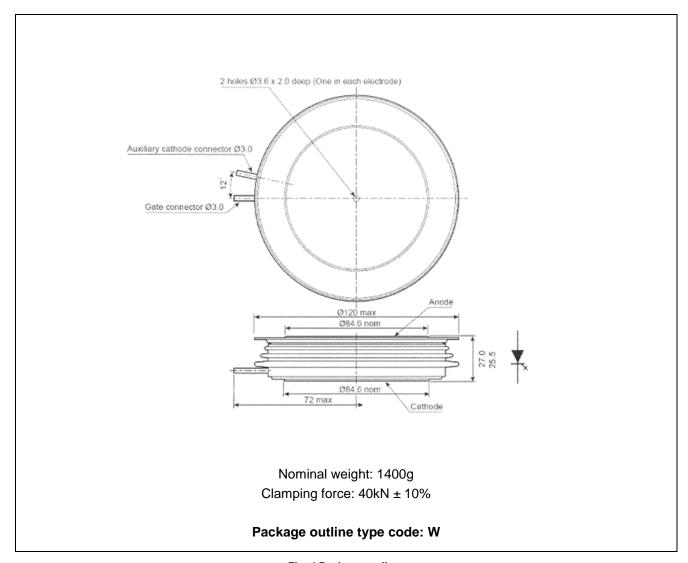


Fig. 4 Package outline

www.dynexsemi.com 6/7

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